

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors



DISCRETE SEMICONDUCTORS

DATA SHEET

BYT79 series Rectifier diodes ultrafast

Product specification

September 1998



NXP Semiconductors Product specification

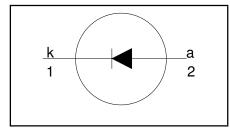
Rectifier diodes ultrafast

BYT79 series

FEATURES

- · Low forward volt drop
- · Fast switching
- · Soft recovery characteristic
- · High thermal cycling performance
- · Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 300 \text{ V} / 400 \text{ V} / 500 \text{ V}$$
 $V_F \le 1.05 \text{ V}$ $I_{F(AV)} = 14 \text{ A}$ $t_{rr} \le 60 \text{ ns}$

GENERAL DESCRIPTION

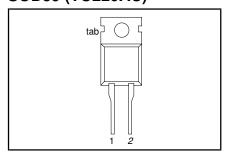
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYT79 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION		
1 0	cathode		
2 a	node		
tab c	athode		
2 a	node		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	. MAX.			UNIT
V _{RRM} V _R	Peak repetitive reverse voltage Continuous reverse voltage	$\textbf{BYT79}$ $T_{mb} \leq 147^{\circ} \textbf{C}$		-300 300 300	-400 400 400	-500 500 500	<<
$I_{F(AV)}$	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \le 117 ^{\circ}\text{C}$	-		14		Α
I _{FSM}	Non-repetitive peak forward current.	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		130 143		A A
T _{stg}	Storage temperature Operating junction temperature	V _{RRM(max)}	-40 -		150 150		Ç

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.0	K/W
R _{th j-a}		in free air.	1	60	1	K/W

¹ Neglecting switching and reverse current losses

NXP Semiconductors Product specification

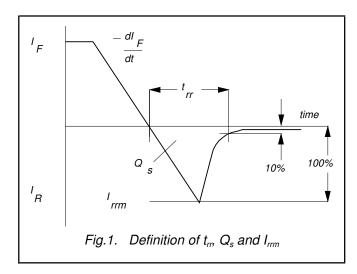
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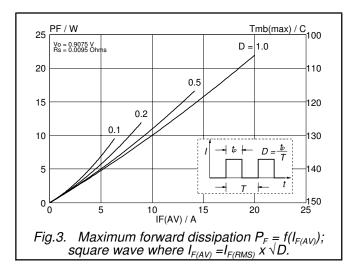
BYT79 series

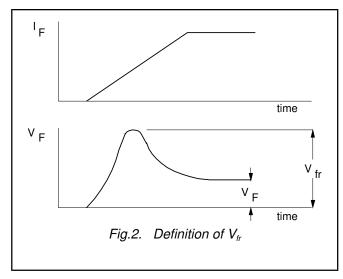
ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage	$I_F = 15 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.90	1.05	V
	_	$I_{\rm F} = 30 \text{A}$	-	1.17	1.38	V
l I _R	Reverse current	$V_R = V_{RRM}$	-	5.0	50	μΑ
		$V_R = V_{RRM}$; $T_i = 100 ^{\circ}C$	-	0.2	0.8	mA
Q_s	Reverse recovery charge	$V_{R} = V_{RRM}^{(n)}; T_{j} = 100 ^{\circ}C$ $I_{F} = 2 ^{\circ}A ^{\circ}to ^{\circ}V_{R} \ge 30 ^{\circ}V;$	-	50	60	nC
		$dI_F/dt = 20 A/\mu s$				
l t _{rr}	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	50	60	ns
		$dI_F/dt = 100 A/\mu s$				
l _{rrm}	Peak reverse recovery current	$I_{\rm F} = 10 \text{ A to } V_{\rm R} \ge 30 \text{ V};$	-	4.0	5.2	Α
		$dI_{F}/dt = 50 \text{ A/µs}; T_{i} = 100 ^{\circ}\text{C}$				
V_{fr}	Forward recovery voltage	$I_F = 10 \text{ A}, dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	2.5	-	V







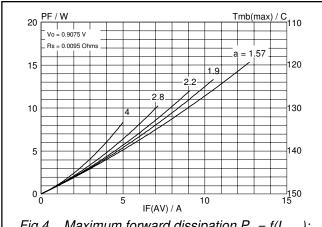
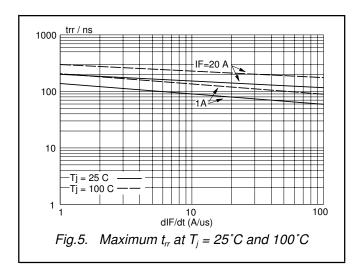


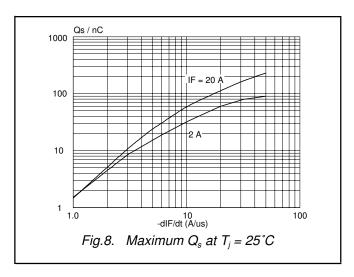
Fig.4. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor $= I_{F(RMS)} / I_{F(AV)}$.

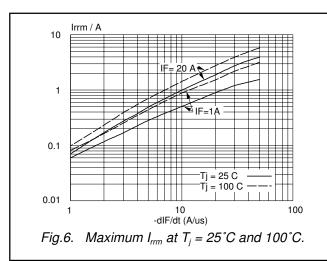
NXP Semiconductors Product specification

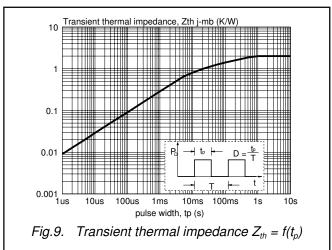
Rectifier diodes ultrafast

BYT79 series









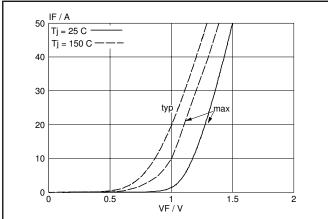


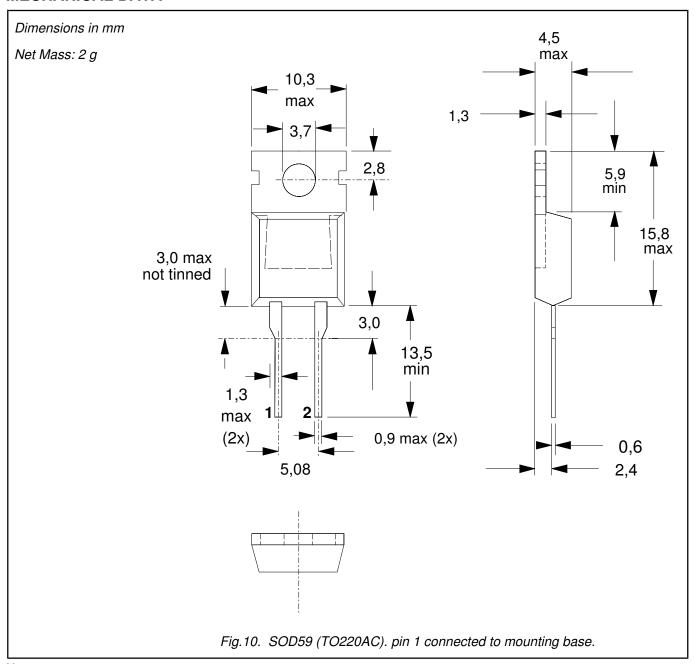
Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

NXP Semiconductors Product specification

Rectifier diodes ultrafast

BYT79 series

MECHANICAL DATA



- Notes
 1. Refer to mounting instructions for TO220 envelopes.
 2. Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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